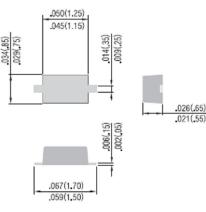


MMBD4448HTS

Surface Mount Switching Diodes

Voltage 100 volts Power 200 mwatts





FEATURES

- Fast switching speed
- Electrically identical to standard JEDEC
- Surface mount package ideally suited for automatic insertion
- High conductance
- Pb free product are available: 99% Sn above can meet RoHS Environment substance directive request

MECHANICAL DATA

Case:SOD-523, plastic case Terminals: Solderable per MIL-STD-750, method 2026 Approx. Weight:0.002 gram Standard packaging: 8mm tape

Unit:inch(mm)

MAXIMUM RATINGS AND ELECTRICAL CHARACTERISTICS

T_J=25°C unless otherwise noted

PARAMETER	SYMBOL	MMBD4448HTS	UNITS
Marking Code		A3	
Reverse Voltage	VR	75	V
Peak Reverse Voltage	Vrm	100	V
RMS Voltage	Vrms	50	V
Maximum DC Blocking Voltage	VDC	75	V
Maximum Average Forward Current at TA=25°C	I _{F(} AV)	150	mA
Peak Forward Surge Current, 1.0 us	IFSM	4	А
Power Dissipation Derate Above 25°C	PD	200	mW
Maximum Forward Voltage	VF	0.72 / 0.005A 1.0 / 0.1A	V
Maximum DC Reverse Current at Rated DC Blocking Voltage TJ= 25°C	lr	2.5@75V	μΑ
Junction Capacitance(Note1)	Сл	4.0	pF
Maximum Reverse Recovery (Note2)	Trr	4.0	ns
Typical Thermal Resistance	R ₀ JA	625	°C /W
Storage Temperature Range	TJ	-55 to +150	°C

NOTES:

1. CJ at V_R =0, f=1MHZ.

2. From I_F =10mA to I_R =1mA, V_R =6 volts, R_L =100 Ω

RATINGS AND CHARACTERISTIC CURVES

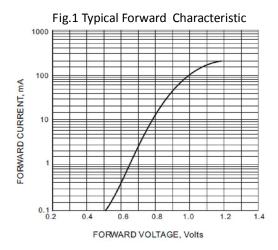


Fig.2 Typical Reverse Characteristics

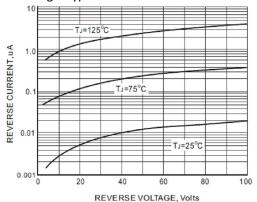


Fig.3 Power Derating Curve

